

For Muting (20V, 0.3A)

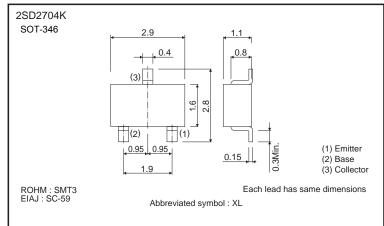
2SD2704K

Features

1) High DC current gain. $h_{FE} = 820$ to 2700 2) High emitter-base voltage. $V_{EBO} = 25V$ (Min.) 3) Low Ron Ron= 0.7Ω (Typ.)

•Structure Epitaxial planar type NPN silicon transistor

•Dimensions (Unit : mm)



Packaging specifications

	Package	Taping
	Code	T146
Туре	Basic ordering unit (pieces)	3000
2SD2704K		0

•Absolute maximum ratings (Ta=25°C)

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Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	50	V
Collector-emitter voltage	Vceo	20	V
Emitter-base voltage	Vebo	25	V
Collector current	lc	0.3	A
Collector power dissipation	Pc	0.2	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	50	-	-	V	Ic=10μA
Collector-emitter breakdown voltage	BVCEO	20	_	-	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	25	_	_	V	Ιε=10μΑ
Collector cutoff current	Ісво	_	_	0.1	μΑ	Vcb=50V
Emitter cutoff current	Іево	-	-	0.1	μΑ	Veb=25V
Collector-emitter saturation voltage	VCE(sat)	-	50	100	mV	Ic/IB=30mA/3mA
DC current transfer ratio	hfe	820	-	2700	-	Vce=2V, Ic=4mA
Transition frequency	f⊤*	-	35	-	MHz	Vce=6V, Ie= -4mA, f=10MHz
Output capacitance	Cob	_	3.9	_	pF	Vcb=10V, Ie=0A, f=1MHz
Output On-resistance	Ron	-	0.7	-	Ω	Iв=5mA, Vi=100mV(rms), f=1kHz

* Measured using pulse current

1000

00

100

COLLECTOR CURRENT : Ic (mA)

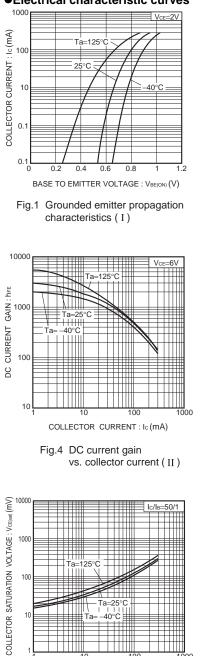
vs. collector current (I)

Fig.3 DC current gain

Ta=12

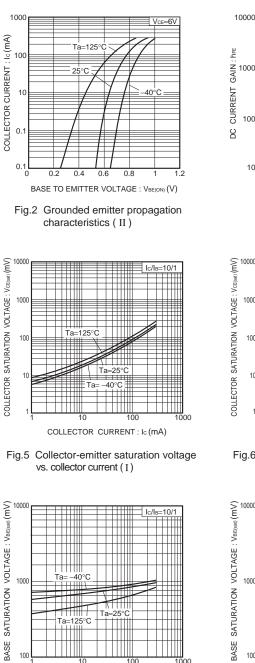
Та 40°C

•Electrical characteristic curves



COLLECTOR CURRENT : Ic (mA) Fig.7 Collector-emitter saturation voltage

vs. collector current (III)



Ta=25°

COLLECTOR CURRENT : Ic (mA)

Fig.8 Base-emitter saturation voltage

vs. collector current (I)

000

100



TIIIII Ta=125

___40°

Та

1000

100

10

1000

1000

100

10

Fig.6 Collector-emitter saturation voltage vs. collector current (II)

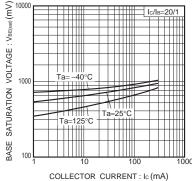
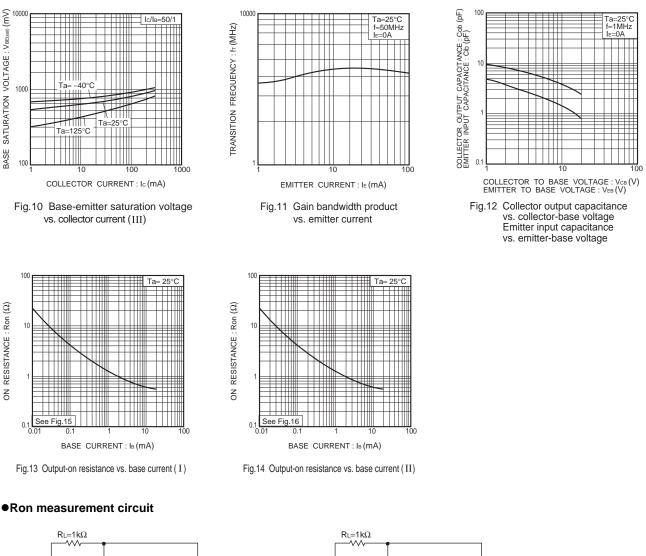


Fig.9 Base-emitter saturation voltage vs. collector current (II)

2SD2704K



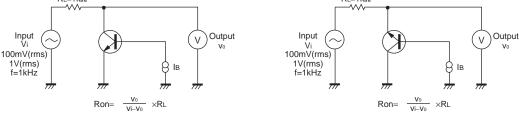
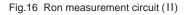


Fig.15 Ron measurement circuit (I)



v

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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